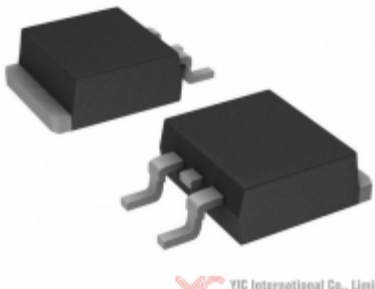










	<h2 style="color: red;">IRFBC20STRL</h2>
	<p>Hersteller-Teilenummer: IRFBC20STRL</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 2.2A D2PAK</p> <p>Datenblätter:  IRFBC20STRL.pdf</p> <p>RoHs Status: Enthält Blei / RoHS nicht konform</p> <p>Lagerzustand: New original, 666 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IRFBC20STRL
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 600V 2.2A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	666 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D2PAK
Verlustleistung (max)	3.1W (Ta), 50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.2A (Tc)
Rds On (Max) @ Id, Vgs	4.4 Ohm @ 1.3A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	18nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	350pF @ 25V
Verpackung	Tape & Reel (TR)



















































IRFBC20STRL ist neu im Original. Suche IRFBC20STRL Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFBC20STRL Vishay / Siliconix mit Garantie und Vertrauen.
Anfrage IRFBC20STRL: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IRFBC20SPBF Vishay / Siliconix MOSFET N-CH 600V 2.2A D2PAK</p>	 <p>IRFBC20S Vishay / Siliconix MOSFET N-CH 600V 2.2A D2PAK</p>	 <p>IRFBC20STRLPBF Vishay / Siliconix MOSFET N-CH 600V 2.2A D2PAK</p>	 <p>IRFBC20STRR Vishay / Siliconix MOSFET N-CH 600V 2.2A D2PAK</p>
 <p>IRFBC20STRLPBF Electro-Films (EFI) / Vishay MOSFET N-CH 600V 2.2A D2PAK</p>	 <p>IRFBC20S Electro-Films (EFI) / Vishay MOSFET N-CH 600V 2.2A D2PAK</p>	 <p>IRFBC20STRR Electro-Films (EFI) / Vishay MOSFET N-CH 600V 2.2A D2PAK</p>	 <p>IRFBC20STRL Electro-Films (EFI) / Vishay MOSFET N-CH 600V 2.2A D2PAK</p>

heiße Teile

Mehr

 IRFB9N30A	 IRFB9N30A	 IRFB9N30APBF	 IRFB9N30APBF	 IRFB9N60A
 IRFB9N60A	 IRFB9N60APBF	 IRFB9N60APBF	 IRFB9N65	 IRFB9N65A
 IRFB9N65A	 IRFB9N65APBF	 IRFB9N65APBF	 IRFBA1404P	 IRFBA1404PPBF
 IRFBA1405P	 IRFBA22N50A	 IRFBC20-030	 IRFBC20LPBF	 IRFBC20LPBF
 IRFBC20PBF	 IRFBC20PBF	 IRFBC20SPBF	 IRFBC20SPBF	 IRFBC20STRL
 IRFBC20STRLPBF	 IRFBC20STRLPBF	 IRFBC20STRR	 IRFBC20STRR	 IRFBC30ALPBF
 IRFBC30ALPBF	 IRFBC30AS	 IRFBC30AS	 IRFBC30ASPBF	 IRFBC30ASPBF
 IRFBC30ASTRL	 IRFBC30ASTRL	 IRFBC30ASTRR	 IRFBC30ASTRR	 IRFBC30ASTRRPBF
 IRFBC30ASTRRPBF	 IRFBC30LPBF	 IRFBC30LPBF	 IRFBC30LTRR	 IRFBC30PBF
 IRFBC30PBF	 IRFBC30S	 IRFBC30S	 IRFBC30STRLPBF	 IRFBC30STRLPBF

Contact us: Info@Y-IC.com

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